pixels of said display device[, wherein said one of said
substrates comprises a plastic.];

- a liquid crystal material disposed between said pair of
 .
 opposed substrates;
- a resin adhesive layer formed on said one of the substrates; and
- a driver circuit comprising thin film transistors that are formed from a <u>stick</u> substrate separate from said substrates <u>and</u> are peeled from said stick substrate after the formation and are adhered to said one of the substrates by said resin adhesive layer.
- 2. (Amended) A liquid crystal display device according to claim 1 wherein said each of thin film transistors has a channel region comprising [crystal] crystalline silicon.
- 7. (Amended) An active matrix type liquid crystal display device comprising:
- a pair of opposed substrates, at least one of said substrates being provided with a pixel circuit for switching pixels of said display device;
- a liquid crystal material disposed between said pair of opposed substrates;

a resin adhesive layer formed on said one of the substrates;

a driver circuit comprising thin film transistors formed from a substrate separate from said one of the substrates and adhered to said one of the substrates by [a] said resin adhesive layer; and

a passivation film covering said driver circuit [, said passivation film] and having a contact hole to allow an electrical connection between at least one of said thin film transistors and said pixel circuit, [and] wherein said contact hole has a tapered configuration.

- 8. (Amended) A liquid crystal display device according to claim 7 wherein said each of thin film transistors has a channel region comprising [crystal] crystalline silicon.
- 17. (Amended) A liquid crystal display device according to claim 15 wherein said each of thin film transistors has a channel region comprising [crystal] crystalline silicon.
- 35. (Amended) A liquid crystal display device according to claim 22 wherein each of said thin film transistors has a channel region comprising [crystal] crystalline silicon.

- 36. (Amended) An active matrix type display device comprising:
 - a substrate [comprising a plastic];
- a pixel circuit formed over said substrate for switching pixels of said display device,
- a driver circuit comprising thin film transistors formed over said substrate and from a stick substrate separate from said substrate, wherein said thin film transistors are coupled in said driver circuit after being peeled from said stick substrate; and
- a resin[,] <u>adhesive layer for</u> adhering said thin film transistors to said substrate.
- 37. (Amended) A display device according to claim 36 wherein said each of thin film transistors has a channel region comprising [crystal] crystalline silicon.
- 46. (Amended) A display device according to claim 44 wherein said each of thin film transistors has a channel region comprising [crystal] crystalline silicon.
- 56. (Amended) A display device according to claim 55 wherein said each of thin film transistors has a channel region comprising [crystal] crystalline silicon.